MARKED MEDIUM EFFECTS ON THE SUBSTITUTION AND THE ADDITION-REARRANGEMENT-EJECTION REACTIONS OF (HALOMETHYL)SILANES WITH METHOXIDES

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Abstract: Reactions of methoxides with (halomethyl)silanes at silicon are facilitated by aprotic solvents and cation separation.

(Chloromethyl)dimethylphenylsilane (1) reacts with sodium ethoxide in ethanol to give (1) (ethoxymethyl)dimethylphenylsilane (3, Eq 1) by displacement of chloride ion from chloromethyl-carbon and (2) ethoxydimethylphenylsilane (6, Eq 2) and chloromethide ion (7) by attack on silicon (5;a) with cleavage. 1a Of particular interest is that benzylethoxydimethylsilane (8) is formed by a process (Eq 3) presumed to involve attack on silicon (5;b) with phenyl migration to chloromethylcarbon and chloride ion ejection. 1a Also, sodium methoxide in methanol reacts with (chloromethyl)dimethylsilanes, Z-(CH₃)₂Si-CH₂-Cl [Z=H, (CH₃)₃Si and

p-ClC₆H₄], possibly via the addition-rearrangement-ejection mechanism of Eq 3, to give products $[CH_3O-Si(CH_3)_2-CH_2-Z; Z=H, (CH_3)_3Si \text{ and } p$ -ClC₆H₄] derived exclusively from migration of the hydrogen, trimethylsilyl and p-chlorophenyl groups. 1b,c Investigation has now been made of the behavior of (bromomethyl)trimethylsilane (9, Eq 4) and 1 with methoxides under various conditions. The studies (1) reveal significant differences in the effects of solvents, metallic cations and temperature on the competitive reactions of 9 and 1 with methoxides and (2) establish that the addition-rearrangement-ejection processes postulated (Eq 3) do indeed involve initial attack of methoxide on silicon in 9.

The behavior of 9 with sodium methoxide (1.2 equiv) in various solvents (Eq 4, Table 1) at reflux temperatures was investigated first. With sodium methoxide in methanol, 9 is converted essentially totally to (methoxymethyl)trimethylsilane (10, 98%). As dioxane is substituted for methanol, the reactions of 9 with methoxide change dramatically in that methoxytrimethylsilane (11), methyl bromide (12) and the rearrangement product,

Table 1: Products (% Yields) from 9 and Sodium Methoxide (Eq 4).

| Solvent | Time, hr | 10 | 11 | 13 |
|--|----------|----|-----|-----|
| сн ₃ он | 19 | 98 | 0.5 | 0 |
| 50% сн ₃ он, с ₄ н ₈ о ₂ | 21 | 96 | 1.2 | 0.3 |
| 5% сн ₃ он, с ₄ н ₈ о ₂ | 18 | 24 | 9 | 60 |
| C4H8O2 | 7 | 1 | 6 | >80 |

ethylmethoxydimethylsilane (13), are formed along with 10. Of further significance is that 13 is by far the major product (60%) of reaction of 9 with sodium methoxide in 5% methanol/dioxane or even more (>80%) in pure dioxane. Excess sodium methoxide, less solvent, shorter reaction times or prolonged heating cause no change in the distribution of the products from 9 and sodium methoxide in dioxane and 10 is stable to sodium methoxide for long periods.

The facts that sodium methoxide reacts with 9 in limited methanol or in dioxane to give rearrangement product 13 essentially exclusively are interpretable on the basis of preferential attack on silicon in the aprotic environments via pentacovalent complex 14, methyl migration and bromide ejection analogous to 5 in Eq 3. Alternate routes to 13 as well as 10 however involve trimethylsilylcarbene (16) as generated by proton abstraction from 9 by methoxide to form 15 followed by (or with) loss of bromide ion. Carbene 16 could then capture methanol to give 10 or undergo methyl migration to 2-methyl-2-sila-2-butene (17) or methyl-C-H insertion to 1,1-dimethyl-1-silacyclopropane (18). Id-f Reaction of 17 and/or 18 with methanol would thus yield 13. Id-g Indeed (chloromethyl)trimethylsilane is converted by lithium 2,2,6,6-tetramethylpiperidide to 16 (or its carbenoid) capturable by electron-rich olefins Ih. Further, photolysis and thermolysis of trimethylsilyldiazomethane [(CH₃)₃SiCH=N₂] give discrete 16, isomerization of which results in 17 and 18. Id-f Reactions of methanol to give 13 are known for 17 Id-f and expected for 18. Ig

Possible alpha-elimination of 9 with rearrangement and/or C-H insertion was then studied with sodium methoxide in dioxane containing methanol-0-D(\sim 5%). If 16-18 were captured by the labelled solvent, 10 and 13 would be formed containing deuterium. Further, if reversible deprotonation of 9 by methoxide were to occur, some deuterium should be in the 9 recovered. Analyses of 9 and 16-18 from many such experiments revealed however that deuterium had not been incorporated, thus eliminating 15-18 as reaction intermediates.

The present study thus reveals that sodium methoxide in dioxane attacks 9 preferentially on silicon presumably via 14^{11} with methyl migration and bromide ejection or with bromomethide (${}^{-}$ CH₂Br) expulsion, whereas in methanol displacement occurs essentially exclusively on

bromomethylcarbon. Since dioxane solvates cations well and anions poorly, it is presumed that "naked" methoxide ion reacts preferably with 9 at silicon, making use of the vacant 3d orbitals and the strength of the developing silicon-oxygen bond. Reaction is then completed by rearrangement-ejection to 13 and bromide ion or collapse to 11 and bromomethide ion.

Methoxide ion in methanol is apparently highly hydrogen-bonded and thus reaction on silicon in 9 would require stripping of the solvent from the oxyanion. Attack of the solvated methoxide nucleophile then occurs by displacement on relatively-sterically available carbon in 9 to give 10.15

The reactions of 1 with sodium methoxide in methanol were then investigated. At 65 °C the major product is (methoxymethyl)dimethylphenylsilane (19, Eq 5; 79%, Table 2) as formed by displacement of chloride ion from chloromethylcarbon of 1. Methoxydimethylphenylsilane

Table 2: Products (% Yields) from 1 and Methoxides (Eq 5 and 6).

| Methoxide | Solvent | Temp., OC | Time, hr | 19 | 20 | 22 | 23 | 24 |
|--------------------|--------------------------------|-----------|----------|----|----|----|----|----|
| NaOCH ₃ | сн3он | 65 | 12 | 79 | 5 | | | 6 |
| NaOCH3 | CH ₃ OH, 18-Crown-6 | 65 | 18 | 60 | 11 | | | 26 |
| косн3 | сн3он | 65 | 12 | 28 | 14 | | | 46 |
| CsOCH3 | сн3он | 65 | 2 | 8 | 20 | | | 66 |
| NaOCH ₃ | $^{\mathrm{C_4H_8O_2}}$ | 30 | 168 | | 3 | 76 | 14 | 3 |
| NaOCH3 | $C_4H_8O_2$ | 60 | 108 | | 6 | 51 | 26 | 16 |
| NaOCH ₃ | $C_4H_8O_2$ | 100 | 12 | | 12 | | 32 | 44 |
| NaOCH3 | C4H8O2, 18-Crown- | -6 30 | 18 | | 10 | | 14 | 76 |

(20, 5%) results from reaction of methoxide on silicon of 1 (as in Eq 3) with loss of 7. Dimethoxydimethylsilane (24, 6%) and toluene (25) are produced by methanolysis of benzylmethoxydimethylsilane (22) as derived by attack of methoxide on silicon of 1 with phenyl migration and chloride loss (as in Eq 3). Addition however of 18-crown-6 ether in trace amounts to 1 and sodium methoxide in methanol or substituting potassium methoxide or cesium methoxide for sodium methoxide causes a dramatic shift in the product distribution (Table 2) from Eq 5 and 6. Upon making the reactant changes progressively, 19 decreases from 79 to 8% while 20 and 24 increase from 11 to 86% and thus there is a shift from predominant methoxide attack on carbon to that on silicon. Also, all of the products from 1 and sodium methoxide in dioxane result from attack of methoxide on silicon and (2) the reactions of 1 with sodium methoxide

are much faster in dioxane than in methanol. Further, 1 in dioxane does not react detectably with lithium methoxide, lithium methoxide containing 12-crown-4 ether, magnesium methoxide or calcium methoxide for long periods at 100 °C.

The differences in the presently observed behavior of 1 obviously stem from the effects of cations, solvation and covalency on methoxide ion as a reactant. 1k 18-Crown-6 ether complexes sodium ion and, upon addition to sodium methoxide in methanol, leads to methoxide ion more effectively separated from its counter cation. The sizes and the ionic stabilities of cesium, potassium and sodium ions are Cs > K > Na and thus the reaction paths of the various alkali-metal methoxides with 1 in methanol (Table 2) reflect the dissociation of the metallic ions in that the more separated methoxides react preferentially on silicon. That sodium methoxide in dioxane reacts with 1 with rapidity and essentially exclusively on silicon emphasizes again the differences in behavior of halomethylsilanes with methoxide in ether and in hydrogen-bonding environments. The lack of reactivity of lithium methoxide and alkaline-earth methoxides with 1 in dioxane illustrates clearly that covalency to methoxide represses nucleophilicity with respect to 1.

Of further interest is that methoxide attack on silicon in 1 in dioxane results in methyl migration and chloride ion ejection to give ethylmethoxymethylphenylsilane (23, Eq 5, Table 2) along with 20-22, 24 and 25. Conversion of 1 to 23 by methoxide in dioxane increases with temperature and is the first example of an alkyl group (methyl) migrating competitively with a phenyl group in rearrangement from anionic pentavalent silicon (at 60 °C the relative migratory ability of phenyl to methyl as statistically corrected is 5:1). The fact that phenyl migrates in preference to methyl in the present systems is consistent with the supposition that the transition states for rearrangement-ejection are close in structure to 5 and thus the group that rearranges preferentially is that which can better support its electron pair (inductively) on departure from silicon. 1a,1

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References and Notes

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